

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirement of Automotive Applications

Features

- BV_{CEO} > 100V
- I_C = 6A High Continuous Collector Current
- I_{CM} = 10A Peak Collector Current
- P_D up to 3.2W
- 43% Smaller than SOT223; 60% Smaller than TO252
- Maximum Height just 1.1mm
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.093 grams (Approximate)

Applications

- Motor Drive
- Voltage Regulator Using Emitter-Follower
- DC-DC Converter
- Telecoms
- Power Management



Ordering Information (Note 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXT2011P5Q-13	Automotive	DXT2011	13	16	5,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes

PowerDI5



DXT2011 = Product Type Marking Code) | = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 for 2017) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated. DXT2011P5Q



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	200	V	
Collector-Emitter Voltage	V _{CEO}	100	V	
Emitter-Base Voltage	V _{EBO}	7	V	
Continuous Collector Current	lc	6	А	
Peak Pulse Current	I _{CM}	10	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		3.2	w	
Power Dissipation	(Note 7)	PD	1.7		
	(Note 8)		0.74		
	(Note 6)		39	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 7)	R _{θJA}	75		
	(Note 8)		169		
Thermal Resistance, Junction to Leads	(Note 9)	R _{θJL}	5.6		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Same as note (6), except mounted on 25mm x 25mm 1oz copper.

8. Same as note (6), except mounted on minimum recommended pad (MRP) layout.

Same as note (0), except moduled on minimum recommended pad (MNP) rayout.
 Thermal resistance from junction to solder-point (on the exposed collector pad).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	200	235	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	100	115	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cutoff Current	ICBO	_	_	20	nA	V _{CB} = 150V
	ICBO	_	—	0.5	μA	V _{CB} = 150V, T _A = +100°C
Collector Cutoff Current	ICER	—		20	nA	V _{CB} = 150V
	R≤1kΩ	_	—	0.5	μA	$V_{CB} = 150V, T_A = +100^{\circ}C$
Emitter Cutoff Current	I _{EBO}	_		10	nA	$V_{EB} = 6V$
			21	35		$I_{C} = 0.1A, I_{B} = 5mA$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(SAT)}	—	50	65	mV	$I_{C} = 1A, I_{B} = 100mA$
	VCE(SAT)	_	95	125	IIIV	$I_{\rm C} = 2A, I_{\rm B} = 100 {\rm mA}$
		-	180	220		$I_{C} = 5A, I_{B} = 500mA$
Base-Emitter Saturation Voltage (Note 11)	VBE(SAT)	_	1020	1120	mV	$I_{C} = 5A, I_{B} = 500mA$
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(ON)}	_	920	1000	mV	$V_{CE} = 2V, I_C = 5A$
		100	_	_	_	$V_{CE} = 2V, I_{C} = 10mA$
DC Current Gain (Note 11)	b	100	—	300	—	$V_{CE} = 2V, I_C = 2A$
	h _{FE}	30	—	—	—	$V_{CE} = 2V, I_C = 5A$
		10	—	—	—	$V_{CE} = 2V, I_{C} = 10A$
Transition Frequency	f _T		130	_	MHz	V _{CE} = 10V, I _C = 100mA, f = 50MHz
Output Capacitance	Cobo		26	_	pF	V _{CB} = 10V, f = 1MHz
Switching Timos	ton	_	41	—	ns	$V_{CC} = 10V, I_C = 1A,$
Switching Times	toff	—	1010	—	115	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 11. Pulse Test: Pulse width \leq 300 $\mu s.$ Duty cycle \leq 2.0%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5



PowerDI5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A1	0.00	0.05			
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2		-	3.054		
ш	6.40	6.60	6.504		
e		-	1.84		
E1	5.30	5.45	5.37		
E2		-	3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	1.840			
G	0.852			
Х	1.390			
X1	3.360			
Y	1.400			
Y1	4.860			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

PowerDI5



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